NSN 5961-01-200-3858

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-200-3858 **Inclosure Material:** Glass **Overall Length:** Between 0.680 inches and 0.720 inches **Mounting Method:** Press fit Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, instantaneous **Capacitance Rating In Picofarads:** 0.017 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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